

PATENT
0941-0839P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: HUANG, Chiu-Tsung et al. Conf.:
Appl. No.: NEW Group:
Filed: September 22, 2003 Examiner:
For: DUAL-BIT NITRIDE READ ONLY MEMORY CELL
WITH PARASITIC AND METHODS OF FABRICATING
AND READING THE SAME

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

September 22, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification

Remarks